

## **IXTH180N10T Datasheet**



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DiGi Electronics Part Number IXTH180N10T-DG

Manufacturer IXYS

Manufacturer Product Number IXTH180N10T

Description MOSFET N-CH 100V 180A TO247

Detailed Description N-Channel 100 V 180A (Tc) 480W (Tc) Through Hole

TO-247 (IXTH)



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DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXTH180N10T	IXYS
Series:	Product Status:
Trench	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
100 V	180A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	6.4mOhm @ 25A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4.5V @ 250μA	151 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	6900 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	480W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 175°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-247 (IXTH)	TO-247-3
Base Product Number:	
IXTH180	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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